

What is claimed is:

1. A semiconductor dynamic quantity sensor comprising:
a support substrate having an opening portion open on a surface thereof;

first and second movable electrode supporting portions fixed to the support substrate;

a movable electrode supported by the first and second movable electrode supporting portions to be displaced in accordance with a dynamic quantity applied thereto;

first and second fixed electrode supporting portions fixed to the support substrate; and

a fixed electrode supported by the first and second fixed electrode supporting portions and facing the movable electrode with a detection interval defined therebetween, the detection interval being changed to detect the dynamic quantity when the movable electrode is displaced,

wherein the first and second movable electrode supporting portions are provided on opposed sides of the opening portion; and

the first and second fixed electrode supporting portions are provided on the opposed sides of the opening portion.

2. The semiconductor dynamic quantity sensor according to claim 1, wherein an axis connecting the first and second movable electrode supporting portions is approximately parallel to an axis connecting the first and second fixed electrode supporting portions.

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7. A semiconductor dynamic quantity sensor comprising:
a support substrate having an opening portion open on a surface thereof;

first and second movable electrode supporting portions fixed to the support substrate;

a movable electrode supported by the first and second movable electrode supporting portions to be displaced in a displacement direction in accordance with a dynamic quantity applied thereto;

first and second fixed electrode supporting portions fixed to the support substrate; and

a fixed electrode supported by the first and second fixed electrode supporting portions and facing the movable electrode with a detection interval defined therebetween, the detection interval being changed to detect the dynamic quantity when the movable electrode is displaced,

wherein the first and second movable electrode supporting portions are arranged in a direction approximately parallel to a direction in which the first and second fixed electrode supporting portions are arranged.

8. The semiconductor dynamic quantity sensor according to claim 7, wherein the direction in which the first and second movable electrode supporting portions and the first and second fixed electrode supporting portions are respectively arranged is approximately parallel to the displacement direction of the

movable electrode.

9. The semiconductor dynamic quantity sensor according to claim 7, wherein:

one of the first and second movable electrode supporting portions and one of the first and second fixed electrode supporting portions are provided on a first side of the opening portion; and

another one of the first and second movable electrode supporting portions and another one of the first and second fixed electrode supporting portions are provided on a second side of the opening portion opposed to the first side.

10. The semiconductor dynamic quantity sensor according to claim 9, wherein the movable electrode and the fixed electrode respectively have pole portions facing each other with the detection interval defined therebetween, the pole portions extending approximately in parallel with the first side and the second side of the opening portion.

11. A semiconductor dynamic quantity sensor comprising:
a frame member;

a movable electrode supported by the frame member through a beam portion to be displaced in a displacement direction by a dynamic quantity applied thereto, the movable electrode having a detection surface; and

a fixed electrode supported by the frame member and having

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a detection surface facing the detection surface of the movable electrode while defining a detection interval that is changed to detect the dynamic quantity when the movable electrode is displaced by the dynamic quantity,

wherein a width of the frame member in the displacement direction of the movable electrode is uniform.

12. The semiconductor dynamic quantity sensor according to claim 11, wherein the frame member is bonded to a base portion through adhesive having a thermal expansion coefficient different from that of the frame member.

13. The semiconductor dynamic quantity sensor according to claim 11, wherein the movable electrode is symmetrical with respect to a centerline of the frame member.

14. The semiconductor dynamic quantity sensor according to claim 11, wherein:

the fixed electrode is composed of a first fixed electrode and a second fixed electrode that are disposed at both sides of the movable electrode and respectively produce a first capacitance and a second capacitance with the movable electrode;

the first capacitance changes in a different direction from that of the second capacitance when the movable electrode is displaced so that a differential capacitance between the first capacitance and the second capacitance is outputted to detect the dynamic quantity; and

a first portion of the frame member supporting the first fixed electrode has a width that is approximately equal to that of a second portion of the frame member supporting the second fixed electrode.

15. The semiconductor dynamic quantity sensor according to claim 11, wherein:

the fixed electrode is composed of first and ^{second} fixed electrodes that are disposed at both sides of the movable electrode;

each of the first and second fixed electrodes has a supporting portion fixed to the frame member and a comb-shaped electrode portion extending from the supporting portion toward the movable electrode; and

the supporting portion of the first fixed electrode and the supporting portion of the second fixed electrode are point-symmetrical with respect to a center of the frame member.

16. The semiconductor dynamic quantity sensor according to claim 11, wherein the frame member is square.

17. The semiconductor dynamic quantity sensor according to claim 11, wherein the frame member has a first frame part supporting an end of the movable electrode and a second frame part supporting another end of the movable electrode; and

the first frame part has a width in the displacement direction that is approximately equal to that of the second frame part.